

Vishay Siliconix

## **Buffered H-Bridge Driver with Integrate MOSFET**

#### **DESCRIPTION**

The Si9988 is an integrated, buffered H-bridge with TTL compatible inputs and the capability of delivering a continuous 0.65 A at  $V_{DD} = 5 V$  (room temperature) at switching rates up to 200 kHz. Internal logic prevents the upper and lower outputs of either half-bridge from being turned on simultaneously. Both outputs may be forced low (for motor braking) by pulling  $\overline{EN}$  to logic high.

The Si9988 is available in both standard and lead (Pb)-free, 8-pin TSSOP packages, specified to operate over a voltage range of 3.8 V to 13.2 V, and the industrial temperature range of - 40 °C to 85 °C (D suffix).

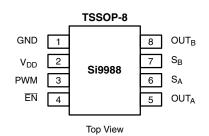
#### **FEATURES**

- 0.65 A H-bridge
- 200 kHz switching rate
- Shoot-through limited
- · TTL compatible inputs
- 3.8 V to 13.2 V operating range
- Surface mount packaging
- Total R<sub>DS(on)</sub> for N- and P-channel: 1.8 at  $V_{DD}$  = 4.5 V and  $T_A$  = 85 °C0.65 A H-bridge

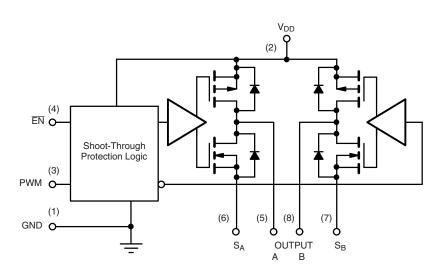
#### **APPLICATIONS**

- VCM driver
- Brushed motor driver
- Stepper motor driver
- Power converter
- Optical disk drives
- Power supplies
- High performance servo

#### FUNCTIONAL BLOCK DIAGRAM, PIN CONFIGURATION AND TRUTH TABLE



TRUT	H TAB	LE	
EN	PWM	OUTA	OUTB
0	0	0	1
0	1	1	0
1	0	0	0
1	1	0	0



ORDERING INFORMA	TION		
Part Number	Marking	Temperature Range	Package
Si9988DQ-T1	988	- 40 °C to 85 °C	Tape and reel
Si9988DQ-T1-E3	900	- 40 C to 65 C	rape and reer

Document Number: 71326 S11-0800-Rev. C, 25-Apr-11

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ABSOLUTE MAXIMUM RATINGS <sup>a</sup>			
Parameter		Limit	Unit
$V_{DD}$		15	
Voltage on any Pin with Respect to Ground		- 0.3 to V <sub>DD</sub> + 0.3	V
Voltage on Pins 5, 8 with Respect to Ground		- 1 to V <sub>DD</sub> + 1	v
Voltage on Pins 6, 7		- 0.3 to GND + 1	
Peak Output Current		1	А
Storage Temperature		- 65 to 150	°C
Junction Temperature (T <sub>J</sub> )		150	
Continuos I <sub>out</sub> Current (T <sub>J</sub> = 135 °C, Y <sub>DD</sub> = 5 V)	T <sub>A</sub> = 25 °C	0.67	^
Continuos i <sub>out</sub> Curient (1) = 135 °C, 1°DD = 5 °V)	T <sub>A</sub> = 85 °C	0.47	A
Power Dissipation <sup>b</sup>		0.83	W
$\theta_{JA}$		120	°C/W
Operating Temperature Range		- 40 to 85	°C

#### Notes:

a. Device mounted with all leads soldered or welded to PC board. b. Derate 8.3 mW/°C above 25 °C. c.  $T_J = T_A + (P_D)(\theta_{JA})$ ,  $P_D = power dissipation$ .

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING RANGE		
Parameter	Limit	Unit
V <sub>DD</sub>	3.8 to 13.2	V
Maximum Junction Temperature (T <sub>J</sub> )	135	°C

SPECIFICATIONS							
Parameter	Symbol	Test Cond Unless Otherwis	e Specified	D Su	Limits ffix, - 40 °C	to 85 °C	Unit
, aramotor	CyDC.	$V_{DD} = 3.8 \text{ to}$ $S_A \text{ at GND, } S_E$		Min <sup>a</sup>	Typ <sup>b</sup>	Max <sup>a</sup>	<b>0</b>
Input (EN, PWM)							
Input Voltage High	$V_{INH}$			2			V
Input Voltage Low	$V_{INL}$					1	V
Input Current with Input Voltage High	I <sub>INH</sub>	V <sub>IN</sub> = 13.	2 V			1	^
Input Current with Input Voltage Low	I <sub>INL</sub>	V <sub>IN</sub> = 0	V	- 1			μΑ
Output							
			V <sub>DD</sub> = 10.8 V	10.55	10.70		
Output Voltage High <sup>c</sup>	$V_{OUTH}$	I <sub>OUT</sub> = - 300 mA	V <sub>DD</sub> = 4.5 V	4.20	4.35		
			V <sub>DD</sub> = 3.8 V	3.40	3.62		V
			V <sub>DD</sub> = 10.8 V		0.09	0.20	V
Output Voltage Low <sup>c</sup>	$V_{OUTL}$	I <sub>OUT</sub> = 300 mA	V <sub>DD</sub> = 4.5 V		0.12	0.25	
			V <sub>DD</sub> = 3.8 V		0.14	0.30	
Output V Clamp High	V <sub>CLH</sub>	EN = PWM ≥ 2 V	I <sub>OUT</sub> = 100 mA		V <sub>DD</sub> + 0.7	V <sub>DD</sub> + 1.0	V
Output V Clamp Low	V <sub>CLL</sub>	EIN = PVVIVI 22 V	I <sub>OUT</sub> = - 100 mA	- 1.0	- 0.7		V
Supply							
		EN = 0 V, PWM = 100	$V_{DD} = 5 V$		1.0	1.5	mA
V <sub>DD</sub> Supply Current	$I_{DD}$	EN = 4.5 V, PWM = 100	) kHz, V <sub>DD</sub> = 5.5 V		60	140	^
		EN = PWM = 4.5 \	$V_{1}, V_{DD} = 5.5 V$		55	110	μΑ

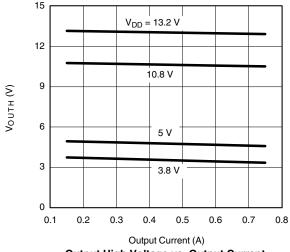


SPECIFICATIONS						
Parameter	Symbol	Test Conditions Unless Otherwise Specified	D Su	Limits ffix, - 40 °C	to 85 °C	Unit
Tarameter	- Cymbol	$V_{DD} = 3.8 \text{ V to } 13.2 \text{ V}$ S <sub>A</sub> at GND, S <sub>B</sub> at GND	Min <sup>a</sup>	Typ <sup>b</sup>	Max <sup>a</sup>	
Dynamic						
Propagation Delay - OUT <sub>A</sub> d	T <sub>PLH</sub>			300		
Propagation Delay - OOTA	T <sub>PHL</sub>			115		
Propagation Delay - OUT <sub>B</sub> d	T <sub>PLH</sub>	$V_{DD} = 5 \text{ V}, \overline{EN} = 0 \text{ V}$		75		nS
Propagation Delay - OOTB	T <sub>PHL</sub>	VDD = 3 V, LIV = 0 V		330		113
Busile Bafaua Malead	BBM <sub>PLH</sub>			225		
Break-Before-Make <sup>d</sup>	BBM <sub>PHL</sub>			215		

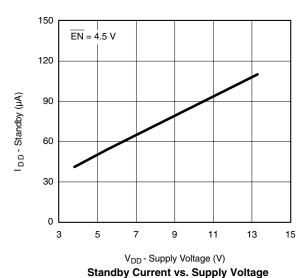
#### Notes:

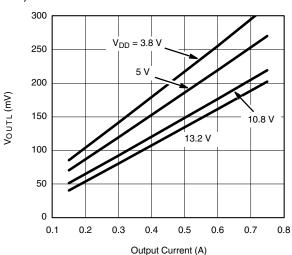
- a. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet. b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing, measured  $T_A = 25 \, ^{\circ}C$ .
- c. Min and Max value measured at  $T_{.1}$  = 135 °C.
- d. PLH = PWM low to high, PHL = PWM high to low.

#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

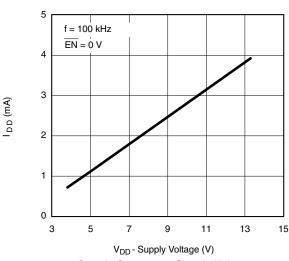






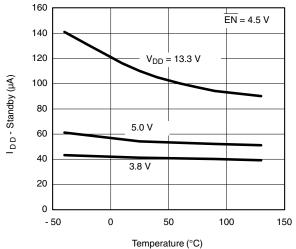


**Output Low Voltage vs. Output Current** 

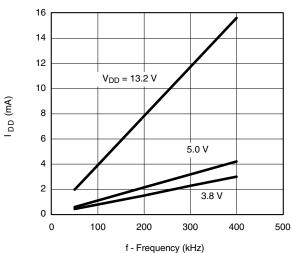


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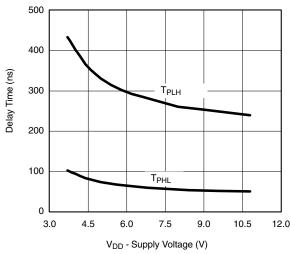
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



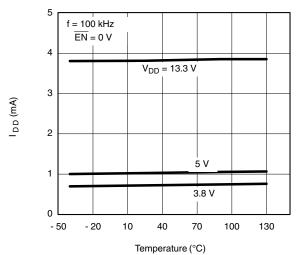
Standby Current vs. Temperature



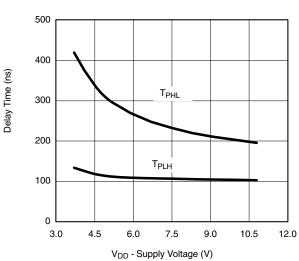
Supply Current vs. Frequency



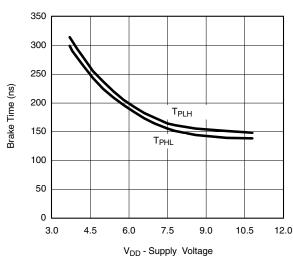
Propagation Time (PWM to OUT<sub>B</sub>) vs. Supply Voltage



Supply Current vs. Temperature



Propagation Time (PWM to OUT<sub>A</sub>) vs. Supply Voltage



Brake\_Before\_Make Time vs. Supply Voltage



#### **TIMING WAVEFORMS**

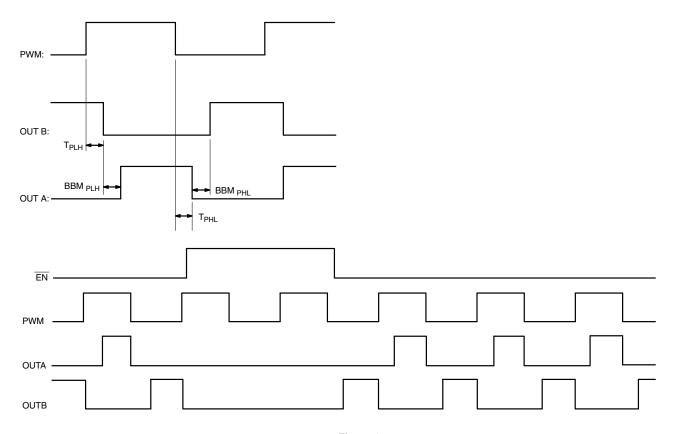


Figure 1.

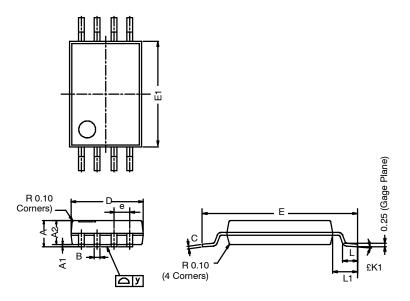
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TSSOP: 8-LEAD (POWER IC ONLY)

JEDEC Part Number: MO-153



	MILLIMETERS				
Dim	Min	Nom	Max		
Α	-	-	1.20		
A <sub>1</sub>	0.05	0.10	0.15		
A <sub>2</sub>	0.80	1.00	1.05		
В	0.19	0.28	0.30		
С	-	0.127	-		
D	2.90	3.00	3.10		
Е	6.20	6.40	6.60		
E <sub>1</sub>	4.30	4.40	4.50		
е	-	0.65	-		
L	0.45	0.60	0.75		
L <sub>1</sub>	0.90	1.00	1.10		
Υ	-	-	0.10		
£K1	0°	3°	6°		

28-Jan-04



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